

View Online at <https://aerobasegroup.com/nsn/5962-01-112-1022>

Maximum Power Dissipation Rating:

76.0 milliwatts

Operating Temperature Range:

-0.0/+80.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and high speed

Inclosure Material:

Ceramic

Inclosure Configuration:

Flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

Dual 4 input

Design Function And Quantity:

2 gate, nand

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Characteristic:

12.00 nanoseconds propagation delay time, low to high level output and 12.00 nanoseconds propagation delay time, high to low level output

Test Data Document:

05869-717129-520 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

14 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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